



TPH3205WSB Information



For Reference Only

Part Number TPH3205WSB **Manufacturer** Transphorm

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description GAN FET 650V 36A TO247

Package TO-247-3

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









TPH3205WSB Specifications

Manufacturer Part Number	TPH3205WSB
Manufacturer	Transphorm
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-247-3
Series	-
FET Type	N-Channel
Technology	GaNFET (Gallium Nitride)
Drain to Source Voltage (Vdss)	650V
Current - Continuous Drain (Id) @ 25°C	36A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	8V
Vgs(th) (Max) @ Id	2.6V @ 700μA
Gate Charge (Qg) (Max) @ Vgs	42nC @ 8V
Input Capacitance (Ciss) (Max) @ Vds	2200pF @ 400V
Vgs (Max)	±18V
FET Feature	-
Power Dissipation (Max)	125W (Tc)
Rds On (Max) @ Id, Vgs	60 mOhm @ 22A, 8V
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-247
Package / Case	TO-247-3
	Report errors?

TPH3205WSB Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

TPH3205WSB Payment Methods



















TPH3205WSB Shipping Methods













If you have any question about TPH3205WSB, please do not hesitate to contact us!

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